

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

11017 U.S. PTO
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In re Patent Application of

BABA et al

Atty. Ref.: 900-421

Serial No. (to be assigned)

Group:

Filed: March 8, 2002

Examiner:

For: SEMICONDUCTOR DEVICE

#4/IDS
5/2/02
VJ

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March 8, 2002

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

INFORMATION DISCLOSURE STATEMENT

As suggested by 37 C.F.R. 1.97, the undersigned attorney brings to the attention of the Patent and Trademark Office the references listed on the attached form PTO-1449, a copy of each of which is enclosed. This is not to be construed as a representation that a search has been made or that no better prior art exists, or that a reference is relevant merely because cited.

The Examiner is requested to initial the attached form PTO-1449 and to return a copy of the initialed document to the undersigned as an indication that the attached references have been considered and made of record.

The undersigned attorney of record hereby certifies under 37 C.F.R. §1.97(e) that each item of information referenced herein and attached hereto was first cited in any

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communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement.

Respectfully submitted,

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**INFORMATION DISCLOSURE
CITATION**

ATTY. DOCKET NO.

SERIAL NO.

900-421

(to be assigned

APPLICANT

BABA et al

FILING DATE

GROUP

(Use several sheets if necessary)

March 8, 2002

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS						TRANSLATION	
	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	YES	NO
	10-321733	12/1998	Patent Abstracts of Japan			Abst.	
	09-219524	08/1997	Patent Abstracts of Japan			Abst.	

OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)

	Wesler et al, "Strain Dependence of the Performance Enhancement in Strained-Si <i>n</i> -MOSFETs", 1994 IEEE, pp. 15.2.1 - 15.2.4.
	Hargrove et al, "Quantum Mechanical Modeling of the Charge Distribution in a Si/Si _{1-x} Ge _x /Si P-Channel MOSFET", 1994 IEEE, pp. 30.3.1 - 30.3.4.
*Examiner	
	Date Considered

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

Form PTO-FB-A820 (Also PTO-1449)